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| APPLICATION NO.                 | FILING DATE               |            | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO.        |  |
|---------------------------------|---------------------------|------------|----------------------|-------------------------|-------------------------|--|
| 10/779,780                      | 0 02/18/2004              |            | Koichi Morikawa      | 031794-12               | 1107                    |  |
| 22204                           | 7590                      | 10/18/2005 |                      | EXAMINER                |                         |  |
| NIXON PE                        |                           | LP         | PHAM, LY D           |                         |                         |  |
| 401 9TH STREET, NW<br>SUITE 900 |                           |            |                      | ART UNIT                | PAPER NUMBER            |  |
| WASHINGT                        | WASHINGTON, DC 20004-2128 |            |                      |                         |                         |  |
|                                 |                           |            |                      | DATE MAILED: 10/18/2005 | DATE MAILED: 10/18/2005 |  |

Please find below and/or attached an Office communication concerning this application or proceeding.

|   | Application No.  | Applicant(s)  |  |  |  |  |  |
|---|--|---|--|--|--|--|--|
|   | 10/779,780   | MORIKAWA, KOICHI  |  |  |  |  |  |
| Office Action Summary   | Examiner   | Art Unit  |  |  |  |  |  |
|   | Ly D. Pham   | 2827  |  |  |  |  |  |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address<br>Period for Reply   |  |   |  |  |  |  |  |
| A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period w  - Failure to repty within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).                            | ATE OF THIS COMMUNICATION 16(a). In no event, however, may a reply be tim rill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONEI | N.<br>nely filed<br>the mailing date of this communication.<br>D (35 U.S.C. § 133). |  |  |  |  |  |
| Status  |  |   |  |  |  |  |  |
| <ul> <li>1) ⊠ Responsive to communication(s) filed on 18 Fe</li> <li>2a) ☐ This action is FINAL. 2b) ⊠ This</li> <li>3) ☐ Since this application is in condition for allowan closed in accordance with the practice under E</li> </ul>  | action is non-final.<br>ace except for formal matters, pro   |   |  |  |  |  |  |
| Disposition of Claims   |  |   |  |  |  |  |  |
| 4) ☐ Claim(s) 1-4 is/are pending in the application. 4a) Of the above claim(s) is/are withdraw 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1 and 3 is/are rejected. 7) ☐ Claim(s) 2 and 4 is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or Application Papers 9) ☐ The specification is objected to by the Examiner 10) ☐ The drawing(s) filed on 18 February 2004 is/are  | election requirement.  | d to by the Examiner.   |  |  |  |  |  |
| Applicant may not request that any objection to the or Replacement drawing sheet(s) including the correction 11) The oath or declaration is objected to by the Expression 11.   | on is required if the drawing(s) is obj  | ected to. See 37 CFR 1.121(d).  |  |  |  |  |  |
| Priority under 35 U.S.C. § 119  |  |   |  |  |  |  |  |
| 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received. |  |   |  |  |  |  |  |
| Attachment(s)  1) \( \sum \) \( \text{Notice of References Cited (PTO-892)} \)  2) \( \sum \) \( \text{Notice of Draftsperson's Patent Drawing Review (PTO-948)} \)  3) \( \sum \) \( \text{Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)} \)  Paper \( \text{No(s)/Mail Date } \frac{02-18-04}{0} \)   | 4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal Pa  |   |  |  |  |  |  |

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## **DETAILED ACTION**

- 1. Applicant's Information Disclosure Statement, IDS, filed February 18, 2004 has been considered by the Examiner.
- 2. Claims 1 4 are pending.

## Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States
- 4. Claims 1 and 3 are rejected under 35 U.S.C. 102(b) as being anticipated by Lewallen et al. (US Pat 4,764,899).

Regarding claims 1 and 3, Lewallen et al. disclose a multi-port semiconductor memory device (figs. 1-3) comprising:

a memory cell array including a plurality of memory cells (fig. 1, array X core cells with an exemplary cell 1);

a first bit line pair performing write-in or read-out of complementary data for the memory cells in the memory cell array (fig. 1, bit line pair BL1 and BL2 coupled to left port read-write circuit 27);

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a second bit line pair performing write-in or read-out of complementary data for the memory cells in the memory cell array (fig. 1, bit line pair BR1 and BR2 coupled to the right port read-write circuit 33);

a plurality of first word lines provided for each of the memory cells for selecting the memory cell that is accessed to the first bit line pair from the memory cell array (fig. 1, exemplary word line 19 is one of the plurality of same in X core cells);

a plurality of second word lines provided for each of the memory cells for selecting the memory cell that is accessed to the second bit line pair from the memory cell array (fig. 1, exemplary word line 21 is one of the plurality of same in X core cells);

a first pull-up circuit (fig. 1, FETs 41 and 43) that pulls up a low-level side of the concerned first bit line pair (col. 4, lines 27 – 37, the bit lines BL1 and BL2 are driven high to nearly logic 1 of about 5 Volts) when data is written in the memory cell that is selected from the first bit line pair (col. 4, lines 37 – 41, "Leakers 39 – 45 are capable of supplying enough current to overcome normal losses of voltage on the bit-lines due to diode leakage, but are not sufficient to raise the voltage on these lines from 0 to 1 in the event that a turned-on transistor is pulling them down to 0—logic low written to a bit line." This corresponds to applicant's specification when logic low is written to bit line BLA to cause it to go low, i.e. 0.9V, even during when pull-up transistors 161 and 162 are on and power line VDD is applied to the port A bit lines BLA, /BLA. See specification page 10, second paragraph.); and

a second pull-up circuit (fig. 1, FETs 39 and 45) that pulls up a low-level side of the concerned second bit line pair when data is written in the memory cell that is

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selected from the second bit line pair (see above for similar discussion on leakers 39

and 45).

Allowable Subject Matter

5. Claims 2 and 4 are objected to as being dependent upon a rejected base claim,

but would be allowable if rewritten in independent form including all of the limitations of

the base claim and any intervening claims.

6. The following is a statement of reasons for the indication of allowable subject

matter:

The prior arts teach the multi-port semiconductor memory as described in claims

1 and 3, except further comprising:

a first regulator circuit and a second regulator circuit that regulate lower power

potential of the memory cell such that the low-level for the first bit line pair and the low-

level of the second bit line pair, respectively, after pull-up is written in the memory cell

as low-level.

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to

applicant's disclosure.

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8. A shortened statutory period for response to this action is set to expire 3 (three)

months and 0 (zero) day from the date of this letter. Failure to respond within the period

for response will cause the application to become abandoned (see MPEP 710.02(b)).

9. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Ly D. Pham whose telephone number is 571-272-1793.

The examiner can normally be reached on Monday-Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Hoai Ho can be reached on 571-272-1777. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

Ly D Pham October 15, 2005

V. Negergen

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VIET Q. NGUYEN PRIMARY EXAMINER